

DDC (LO-R1) H

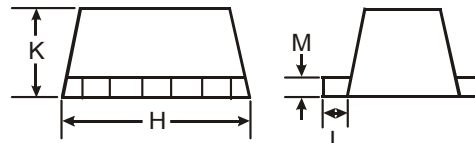
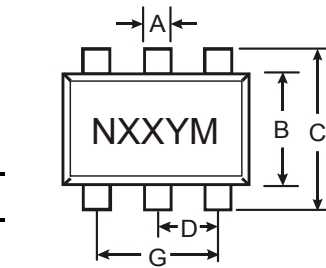
NPN PRE-BIASED SMALL SIGNAL DUAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDA)
- Built-In Biasing Resistors
- **Lead Free By Design/RoHS Compliant (Note 3)**
- **"Green" Device (Note 4 and 5)**

Mechanical Data

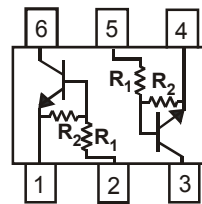
- Case: SOT-563, Molded Plastic
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.005 grams (approximate)



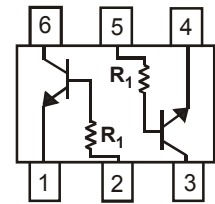
SEE NOTE 1

SOT-563			
Dim	Min	Max	Typ
A	0.15	0.30	0.25
B	1.10	1.25	1.20
C	1.55	1.70	1.60
D	0.50		
G	0.90	1.10	1.00
H	1.50	1.70	1.60
K	0.56	0.60	0.60
L	0.15	0.25	0.20
M	0.10	0.18	0.11
All Dimensions in mm			

P/N	R1 (NOM)	R2 (NOM)	MARKING
DDC122LH	0.22K Ω	10K Ω	N81
DDC142JH	0.47K Ω	10K Ω	N82
DDC122TH	0.22K Ω	OPEN	N83
DDC142TH	0.47K Ω	OPEN	N84



R₁, R₂



R₁ Only

SCHEMATIC DIAGRAM, TOP VIEW

Maximum Ratings

@T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage (6) to (1) and (3) to (4)	V _{CC}	50	V
Input Voltage (2) to (1) and (5) to (4)	V _{IN}	-5 to +6	V
Input Voltage (1) to (2) and (4) to (5)	V _{EBO} (MAX)	5	V
Output Current	I _C	100	mA
Power Dissipation	P _d	150	mW
Thermal Resistance, Junction to Ambient Air (Note 2)	R _{θJA}	833	°C/W

- Notes:
1. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).
 2. Mounted on FR4 Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.
 3. No purposefully added lead.
 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants

Electrical Characteristics @T_A = 25°C unless otherwise specified R1, R2 Types

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDC122LH DDC142JH	V _{I(off)}	0.3	—	—	V	V _{CC} = 5V, I _O = 100μA
	DDC122LH DDC142JH	V _{I(on)}	—	—	2.0 2.0	V	V _O = 0.3V, I _O = 20mA V _O = 0.3V, I _O = 20mA
Output Voltage		V _{O(on)}	—	—	0.3V	V	I _O /I _I = 5mA/0.25mA
Input Current	DDC122LH DDC142JH	I _I	—	—	28 13	mA	V _I = 5V
Output Current		I _{O(off)}	—	—	0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	DDC122LH DDC142JH	G _I	56 56	—	—	—	V _O = 5V, I _O = 10mA
Gain-Bandwidth Product*		f _T	—	200	—	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

* Transistor - For Reference Only

Electrical Characteristics @T_A = 25°C unless otherwise specified R1-Only

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV _{CBO}	50	—	—	V	I _C = 50μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	40	—	—	V	I _C = 1mA
Emitter-Base Breakdown Voltage	DDC122TH DDC142TH	BV _{EBO}	5	—	—	V	I _E = 50μA I _E = 50μA
Collector Cutoff Current		I _{CBO}	—	—	0.5	μA	V _{CB} = 50V
Emitter Cutoff Current	DDC122TH DDC142TH	I _{EBO}	—	—	0.5 0.5	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	—	—	0.3	V	I _C = 5mA, I _B = 0.25mA
DC Current Transfer Ratio	DDC122TH DDC142TH	h _{FE}	100 100	250 250	600 600	—	I _C = 1mA, V _{CE} = 5V
Gain-Bandwidth Product*		f _T	—	200	—	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz

* Transistor - For Reference Only

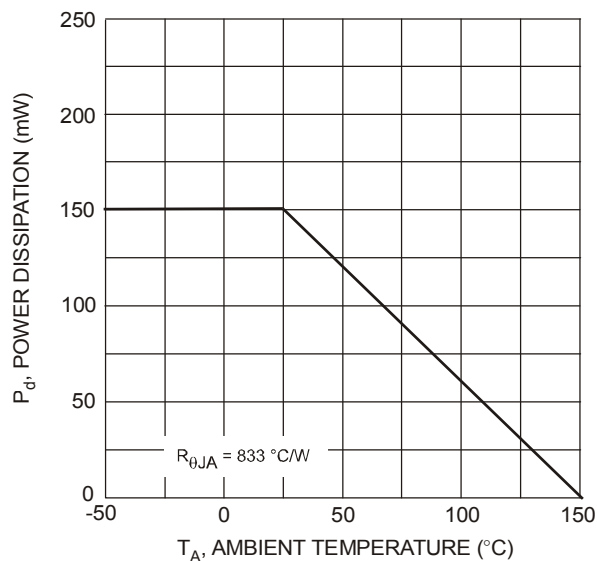


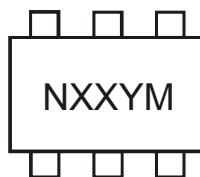
Fig. 1 Derating Curve

Ordering Information (Note 6)

Device	Packaging	Shipping
DDC122LH-7	SOT-563	3000/Tape & Reel
DDC142JH-7	SOT-563	3000/Tape & Reel
DDC122TH-7	SOT-563	3000/Tape & Reel
DDC142TH-7	SOT-563	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



NXX = Product Type Marking Code (See Page 1)

YM = Date Code Marking

Y = Year ex: T = 2006

M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	N	P	R	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9